

# MSKSEMI 美森科

SEMICONDUCTOR



ESD



TVS



TSS



MOV



GDT



PLED

## ES0603V014CT-MS

Product specification

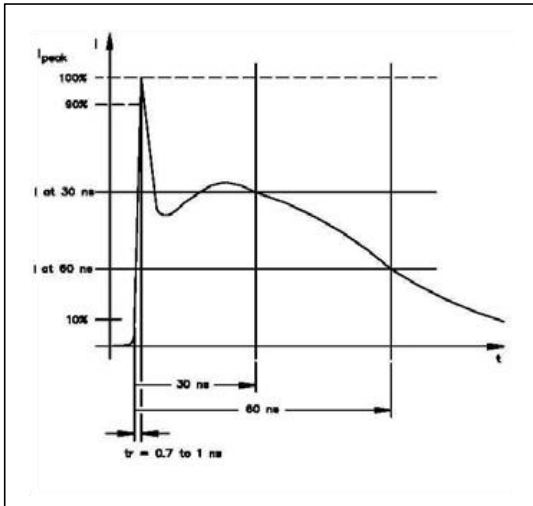
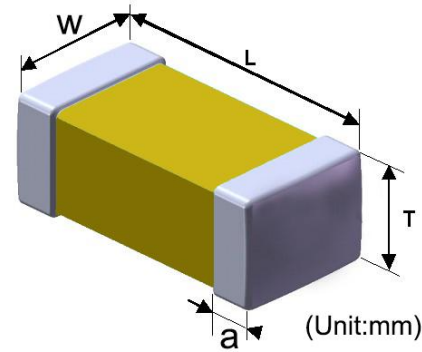
1.1 Technology Data	Symbol	Value	Unit
Maximum allowable continuous AC voltage at 50-60Hz	$V_{RMS}$	18	V
Maximum allowable continuous DC voltage	$V_{DC}$	14	V
Varistor voltage measured <sup>·1</sup>	$V_V$	100~150	V
Typical capacitance value measured at 1MHz	C	0.2	pF
Typical capacitance value tolerance		+80-20	%
Maximum ESD allowable clamping Voltage <sup>·2</sup>	$V_{CLAMP}$ <	240	V
Leakage current at $V_{DC}$ <sup>·3</sup> (At initial state)	$I_{LDC}$ <	0.1	uA
Leakage current at $V_{DC}$ <sup>·3</sup> (After ESD Test)	$I_{LDCA}$ <	2	uA
1.2 Reference Data			
Response time	$T_{rise}$ <	0.5	ns
Operation ambient temperature		-50~ +85	°C
Storage temperature		-50~+125	°C
ESD testing	IEC61000-4-2	Level 4	
1.3 Other Data			
Body		ZnO	
End termination		Ag/Ni/Sn	
Packaging		Reel	
Complies with Standard		IEC61000-4-2	
Complies with RoHs Standard		Yes	
Lead Content	<	1000	ppm
Marking		None	

**Notes:**

- 1 The varistor voltage was measured at 1 mA current
- 2 The Clamping voltage was measured at 8\*20 us standard current.
- 3 The Leakage current was measured at working voltage.
- 4 The Energy only for customer reference.
- 5 The components shall be employed within 1 year, in the nitrogen condition.

**2 .Size**

<b>Model</b>	<b>0603(1608)</b>
Length(L)	1.60±0.15
Width(W)	0.80±0.10
Thickness(T)	0.90 max
Termination( a)	0.3±0.1



**IEC61000-4-2 Standards**

SEVERITY LEVEL	AIRDIRCHARGE	DIRECT DISCHARGE
1	2 KV	2 KV
2	4 KV	4 KV
3	8 KV	6 KV
4	15 KV	8 KV

**IEC 61000-4-2 Compliant ESD Current Pulse Waveform**

**4. Environment Reliability Test**

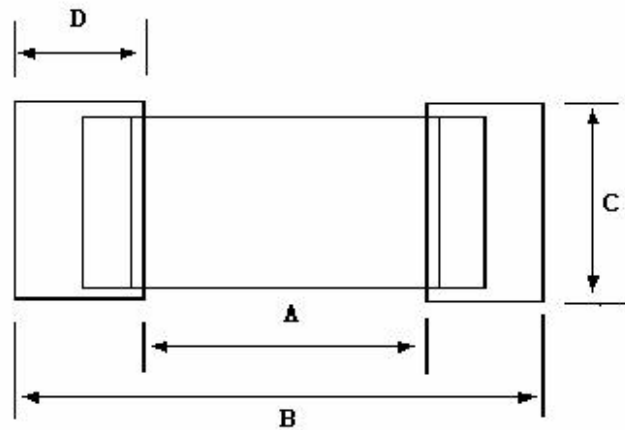
Characteristic	Test method and description			
High Temperature Storage	The specimen shall be subjected to 125 ± 2°C for 1000 ± 12 hours in a thermostatic bath without load and then stored at room temperature and normal humidity for 1 to 2 hours. The change of varistor voltage shall be within 10 % .			
Temperature Cycle	The temperature cycle of specified temperature shall be repeated five times and then stored at room temperature and normal humidity for one or two hours. The change of varistor voltage shall be within 10 % and mechanical damage shall be examined.	Step	Temperature	Period
		1	-40±3°C	30Min±3
		2	Room Temperature	1 hour
		3	125±3°C	30Min±3
4	Room Temperature	1 hour		
High Temperature Load	After being continuously applied the maximum allowable voltage at 85 ± 2°C for 1000± 2 hours, the specimen shall be stored at room temperature and normal humidity for one or two hours, the change of varistor voltage shall be within 10% .			
Damp Heat Load/ Humidity Load	The specimen should be subjected to 40 ± 2°C , 90 to 95 % RH environment, and the maximum allowable voltage applied for 1000 hours, then stored at room temperature and normal humidity for one or two hours. The change of varistor voltage shall be within 10%			
Low Temperature Storage	The specimen should be subjected to -40 ± 2°C , without load for 500 hours and then stored at room temperature for one or two hours. The change of varistor voltage shall be within 10 %			

## 5. Soldering Recommendations

### 5.1 Recommended solder pad layout

(Unit: mm)

	A	B	C	D
0603	0.9~1.2	2.7~3.2	0.7~1.0	0.9~1.2

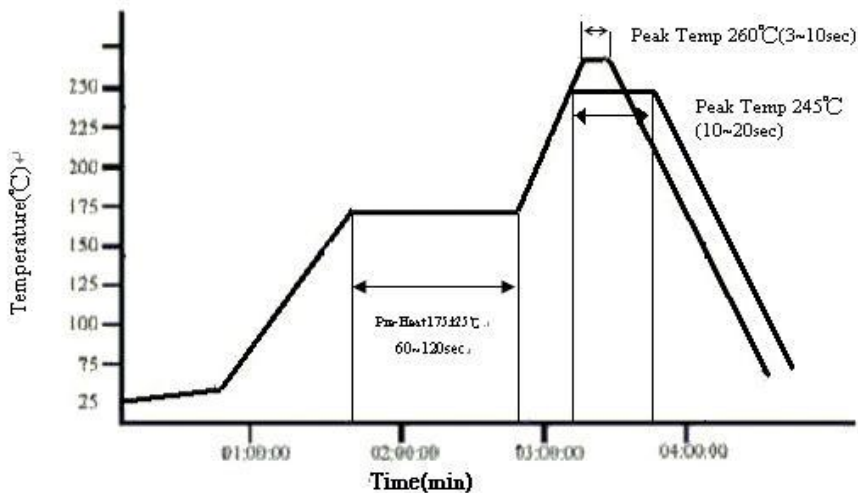


### 5.2 The SIR test of the solder paste shall be done (Based on JIS-Z-3284)

### 5.3 Steel plate and foot distance printing

Foot distance printing (mm)	Steel Plate thickness (mm)
> 0.65mm	0.18mm
0.65mm~0.5mm	0.15mm
0.50mm~0.40mm	0.12mm
>=0.40 mm	0.10mm

### 5.4 The IR reflow and temperature of Soldering for Pb Free



#### ● IR reflow Pb Free Process suggestion profile

- (1) The solder recommend is Sn96.5/Ag 3.5 of 120 to 150 $\mu$ m
- (2) Ramp-up rate (217 $^{\circ}$ C to Peak) + 3 $^{\circ}$ C/second max
- (3) Temp. maintain at 175 +/-25C 180 seconds max
- (4) Temp. maintain above 217  $^{\circ}$ C 60-150 seconds

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